To our customers,

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HZM-N Series

Silicon Epitaxial Planar Zener Diode for Stabilizer

REJ03G0483-0500
(Previous: ADE-208-130D)
Rev.5.00
Dec 14, 2004

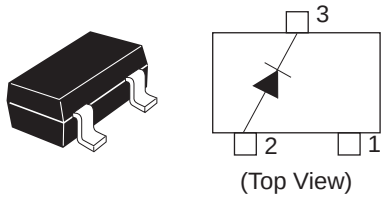
Features

- Wide spectrum from 1.9 V through 38 V of zener voltage provide flexible application.
- MPAK Package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HZM-N Series	Let to Mark Code	MPAK

Pin Arrangement



(Top View)

1. NC
2. Anode
3. Cathode

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Power dissipation	Pd *[1]	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	−55 to +150	°C

Note: 1. See Fig. 3.

Electrical Characteristics

(Ta = 25°C)

Type	Grade	Zener Voltage			Reverse Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (μA)	Test Condition	r_d (Ω)	Test Condition
		Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZM2.0N	B	1.90	2.20	5	120	0.5	100	5
HZM2.2N	B	2.10	2.40	5	120	0.7	100	5
HZM2.4N	B	2.30	2.60	5	120	1.0	100	5
HZM2.7N	B	2.50	2.90	5	120	1.0	110	5
	B1	2.50	2.75					
	B2	2.65	2.90					
HZM3.0N	B	2.80	3.20	5	50	1.0	120	5
	B1	2.80	3.05					
	B2	2.95	3.20					
HZM3.3N	B	3.10	3.50	5	20	1.0	130	5
	B1	3.10	3.35					
	B2	3.25	3.50					
HZM3.6N	B	3.40	3.80	5	10	1.0	130	5
	B1	3.40	3.65					
	B2	3.55	3.80					
HZM3.9N	B	3.70	4.10	5	10	1.0	130	5
	B1	3.70	3.97					
	B2	3.87	4.10					
HZM4.3N	B	4.01	4.48	5	10	1.0	130	5
	B1	4.01	4.21					
	B2	4.15	4.34					
	B3	4.28	4.48					
HZM4.7N	B	4.42	4.90	5	10	1.0	130	5
	B1	4.42	4.61					
	B2	4.55	4.75					
	B3	4.69	4.90					
HZM5.1N	B	4.84	5.37	5	5	1.5	130	5
	B1	4.84	5.04					
	B2	4.98	5.20					
	B3	5.14	5.37					
HZM5.6N	B	5.31	5.92	5	5	2.5	80	5
	B1	5.31	5.55					
	B2	5.49	5.73					
	B3	5.67	5.92					

Note: 1. Tested with pulse (P_W = 40 ms)

Type	Grade	Zener Voltage			Reverse Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (μA)	Test Condition	r_d (Ω)	Test Condition
		Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZM6.2N	B	5.86	6.53	5	2	3.0	50	5
	B1	5.86	6.12					
	B2	6.06	6.33					
	B3	6.26	6.53					
HZM6.8N	B	6.47	7.14	5	2	3.5	30	5
	B1	6.47	6.73					
	B2	6.65	6.93					
	B3	6.86	7.14					
HZM7.5N	B	7.06	7.84	5	2	4.0	30	5
	B1	7.06	7.36					
	B2	7.28	7.60					
	B3	7.52	7.84					
HZM8.2N	B	7.76	8.64	5	2	5.0	30	5
	B1	7.76	8.10					
	B2	8.02	8.36					
	B3	8.28	8.64					
HZM9.1N	B	8.56	9.55	5	2	6.0	30	5
	B1	8.56	8.93					
	B2	8.85	9.23					
	B3	9.15	9.55					
HZM10N	B	9.45	10.55	5	2	7.0	30	5
	B1	9.45	9.87					
	B2	9.77	10.21					
	B3	10.11	10.55					
HZM11N	B	10.44	11.56	5	2	8.0	30	5
	B1	10.44	10.88					
	B2	10.76	11.22					
	B3	11.10	11.56					
HZM12N	B	11.42	12.60	5	2	9.0	35	5
	B1	11.42	11.90					
	B2	11.74	12.24					
	B3	12.08	12.60					
HZM13N	B	12.47	13.96	5	2	10.0	35	5
	B1	12.47	13.03					
	B2	12.91	13.49					
	B3	13.37	13.96					
5M15N	B	13.84	15.52	5	2	11.0	40	5
	B1	13.84	14.46					
	B2	14.34	14.98					
	B3	14.85	15.52					
HZM16N	B	15.37	17.09	5	2	12.0	40	5
	B1	15.37	16.01					
	B2	15.85	16.51					
	B3	16.35	17.09					
HZM18N	B	16.94	19.03	5	2	13.0	45	5
	B1	16.94	17.70					
	B2	17.56	18.35					
	B3	18.21	19.03					

Note: 1. Tested with pulse (P_W = 40 ms)

Type	Grade	Zener Voltage			Reverse Current		Dynamic Resistance	
		V_Z (V)*[1]		Test Condition	I_R (μA)	Test Condition	r_d (Ω)	Test Condition
		Min	Max	I_Z (mA)	Max	V_R (V)	Max	I_Z (mA)
HZM20N	B	18.86	21.08	5	2	15.0	50	5
	B1	18.86	19.70					
	B2	19.52	20.39					
	B3	20.21	21.08					
HZM22N	B	20.88	23.17	5	2	17.0	55	5
	B1	20.88	21.77					
	B2	21.54	22.47					
	B3	22.23	23.17					
HZM24N	B	22.93	25.57	5	2	19.0	60	5
	B1	22.93	23.96					
	B2	23.72	24.78					
	B3	24.54	25.57					
HZM27N	B	25.10	28.90	2	2	21.0	70	2
HZM30N	B	28.00	32.00	2	2	23.0	80	2
HZM33N	B	31.00	35.00	2	2	25.0	80	2
HZM36N	B	34.00	38.00	2	2	27.0	90	2

Note: 1. Tested with pulse (P_W = 40 ms)

Mark Code

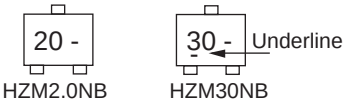
Type	Grade	Mark No.
HZM2.0N	B	2 0 –
HZM2.2N	B	2 2 –
HZM2.4N	B	2 4 –
HZM2.7N	B1	2 7 1
	B2	2 7 2
HZM3.0N	B1	3 0 1
	B2	3 0 2
HZM3.3N	B1	3 3 1
	B2	3 3 2
HZM3.6N	B1	3 6 1
	B2	3 6 2
HZM3.9N	B1	3 9 1
	B2	3 9 2
HZM4.3N	B1	4 3 1
	B2	4 3 2
	B3	4 3 3
HZM4.7N	B1	4 7 1
	B2	4 7 2
	B3	4 7 3
HZM5.1N	B1	5 1 1
	B2	5 1 2
	B3	5 1 3
HZM5.6N	B1	5 6 1
	B2	5 6 2
	B3	5 6 3

Type	Grade	Mark No.
HZM6.2N	B1	6 2 1
	B2	6 2 2
	B3	6 2 3
HZM6.8N	B1	6 8 1
	B2	6 8 2
	B3	6 8 3
HZM7.5N	B1	7 5 1
	B2	7 5 2
	B3	7 5 3
HZM8.2N	B1	8 2 1
	B2	8 2 2
	B3	8 2 3
HZM9.1N	B1	9 1 1
	B2	9 1 2
	B3	9 1 3
HZM10N	B1	1 0 1
	B2	1 0 2
	B3	1 0 3
HZM11N	B1	1 1 1
	B2	1 1 2
	B3	1 1 3
HZM12N	B1	1 2 1
	B2	1 2 2
	B3	1 2 3

Type	Grade	Mark No.
HZM13N	B1	1 3 1
	B2	1 3 2
	B3	1 3 3
HZM15N	B1	1 5 1
	B2	1 5 2
	B3	1 5 3
HZM16N	B1	1 6 1
	B2	1 6 2
	B3	1 6 3
HZM18N	B1	1 8 1
	B2	1 8 2
	B3	1 8 3
HZM20N	B1	2 0 1
	B2	2 0 2
	B3	2 0 3
HZM22N	B1	2 2 1
	B2	2 2 2
	B3	2 2 3
HZM24N	B1	2 4 1
	B2	2 4 2
	B3	2 4 3
HZM27N	B	2 7 –
HZM30N	B	3 0 –
HZM33N	B	3 3 –
HZM36N	B	3 6 –

Example of Marking

1. One grade type (grade type B)



HZM2.0NB HZM30NB

2. Two grade type (B1, B2)

HZM3.0NB1 HZM3.0NB2

3. Three grade type (B1, B2, B3)

HZM4.3NB1 HZM4.3NB2 HZM4.3NB3

Notes: 1. The grade B type includes from B1 min. to B3 (or B2) max.
2. B grade is standard and has better delivery, These are marked one of B1, B2, B3.
3. Ordering P/N HZM-N series are delivered taped (TL/TR).
Choose one taping code and adhere to parts No.
Example: HZM2.0NBTL (or TR), HZM2.2NBTL (or TR), HZM36NBTL (or TR).
(Grade B type)
HZM2.7NB1TL (or TR), HZM2.7NB2TL (or TR), HZM24NB3TL (or TR).
(Grade B1, B2, B3 type)

Main Characteristic

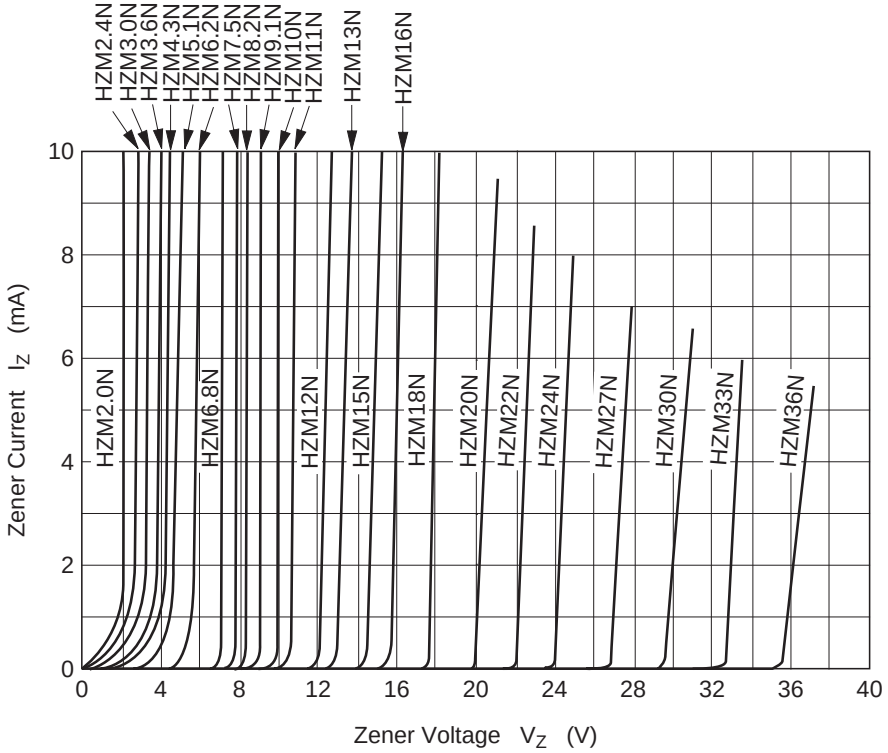


Fig.1 Zener current vs. Zener voltage

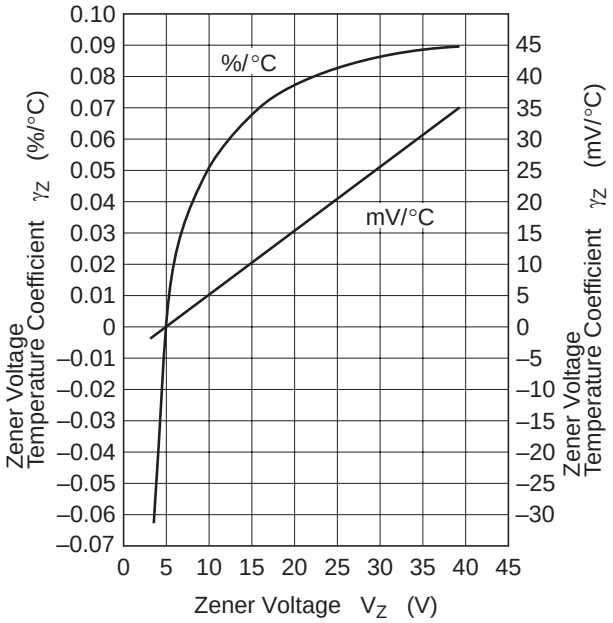


Fig.2 Temperature Coefficient vs. Zener voltage

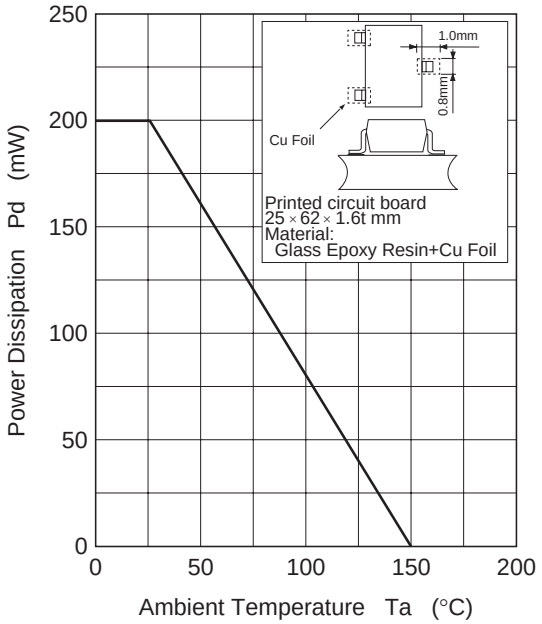
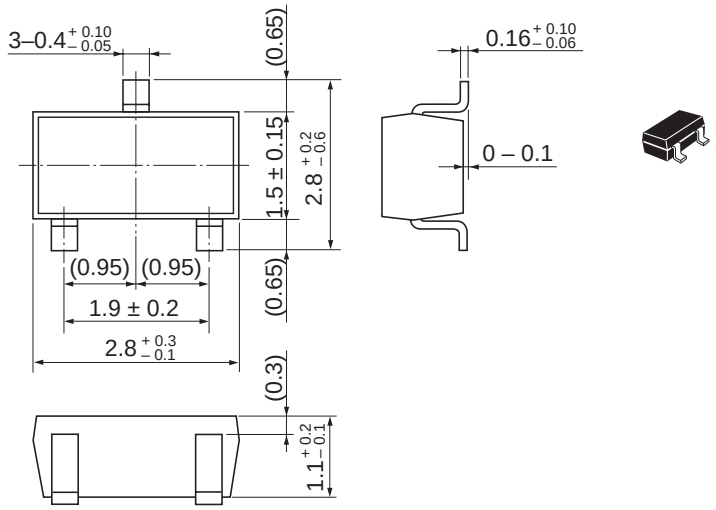


Fig.3 Power Dissipation vs. Ambient Temperature

Package Dimensions

As of January, 2003

Unit: mm



Package Code	MPAK
JEDEC	—
JEITA	Conforms
Mass (reference value)	0.011 g

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